

Description

The VSM3401BY uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

General Features

• $V_{DS} = -30V, I_{D} = -4.4A$

 $R_{DS(ON)}$ < 70m Ω @ V_{GS} =-2.5V

 $R_{DS(ON)} < 55 \text{m}\Omega$ @ V_{GS} =-4.5V

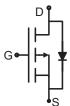
 $R_{DS(ON)}$ < 45m Ω @ V_{GS} =-10V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- PWM applications
- Load switch
- Power management





SOT-23-3

Schematic Diagram

Package Marking And Ordering Information

De	evice Marking	Device	Device Package	Reel Size	Tape width	Quantity
VS	SM3401BY-S2	VSM3401BY	SOT-23-3	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	-30	V	
Gate-Source Voltage	V _{GS}	±12	V	
Drain Current-Continuous	I _D	-4.4	Α	
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	-3.1	Α	
Drain Current-Pulsed (Note 1)	I _{DM}	-30	Α	
Maximum Power Dissipation	P _D	1.3	W	
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 150	$^{\circ}$	

Thermal Characteristic

Thermal Resistance,Junction-to-Ambient (Note 2)	R _{θJA}	96	°C/W
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Electrical Characteristics (T_A=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit		
Off Characteristics								
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V I_D =-250 μ A	-30		-	V		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-24V,V _{GS} =0V	-	-	-1	μΑ		
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA		
On Characteristics (Note 3)								
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.6	-0.9	-1.2	V		



Parameter	Symbol	Condition	Min	Тур	Max	Unit		
	R _{DS(ON)}	V _{GS} =-10V, I _D =-4A	-	33	45	mΩ		
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-3A	-	37.5	55	mΩ		
		V _{GS} =-2.5V, I _D =-2A		55	70	mΩ		
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-4A	-	10	-	S		
Dynamic Characteristics (Note4)								
Input Capacitance	C _{lss}	\/ 45\/\\ 0\/	-	909.5	ı	PF		
Output Capacitance	C _{oss}	V _{DS} =-15V,V _{GS} =0V, F=1.0MHz	-	90.3	ı	PF		
Reverse Transfer Capacitance	C _{rss}	F-1.UIVID2		71	ı	PF		
Switching Characteristics (Note 4)								
Turn-on Delay Time	t _{d(on)}		-	7	-	nS		
Turn-on Rise Time	t _r	V _{DD} =-15V,I _D =-4A	-	3.5	-	nS		
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =-10 V , R_{GEN} =6 Ω	-	35	-	nS		
Turn-Off Fall Time	t _f		-	10	-	nS		
Total Gate Charge	Qg		-	7.3	-	nC		
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-4A,V _{GS} =-4.5V	-	1.1	-	nC		
Gate-Drain Charge	Q _{gd}		-	2	-	nC		
Drain-Source Diode Characteristics								
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-4A	-	-	-1.2	V		

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- Surface Mounted on FR4 Board, t ≤ 10 sec.
 Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

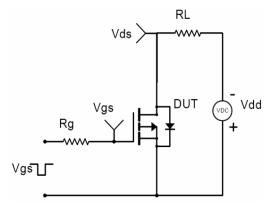


Figure 1:Switching Test Circuit

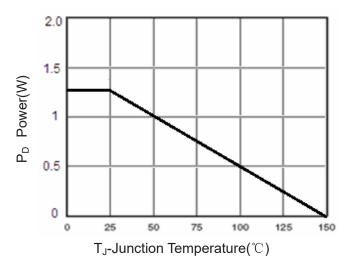
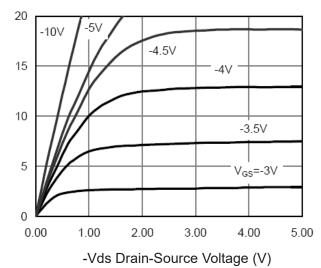


Figure 3 Power Dissipation



-I_D- Drain Current (A)

Figure 5 Output Characteristics

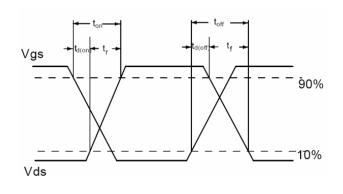


Figure 2:Switching Waveforms

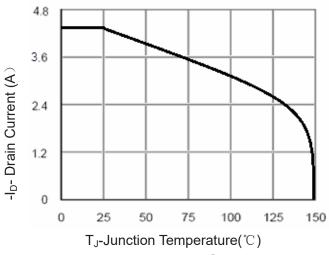


Figure 4 Drain Current

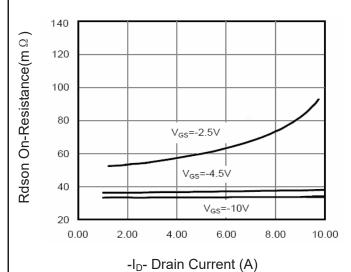


Figure 6 Drain-Source On-Resistance



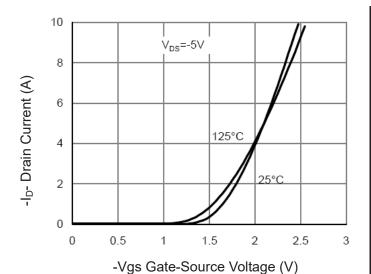
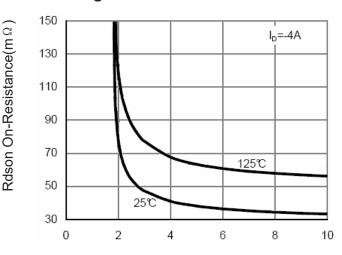


Figure 7 Transfer Characteristics



-Vgs Gate-Source Voltage (V)

Figure 9 Rdson vs Vgs

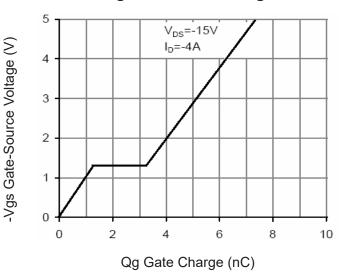
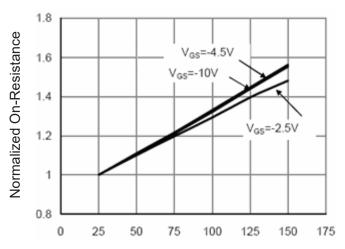
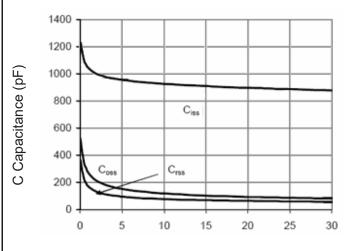


Figure 11 Gate Charge



 T_J -Junction Temperature($^{\circ}$ C)

Figure 8 Drain-Source On-Resistance



-Vds Drain-Source Voltage (V)

Figure 10 Capacitance vs Vds

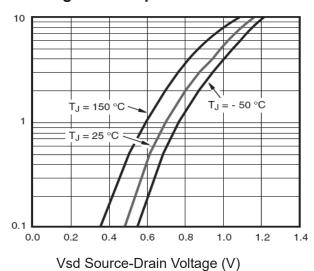
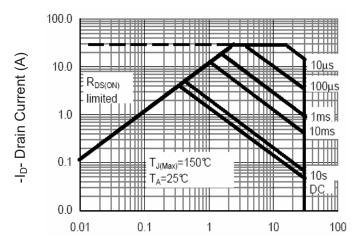


Figure 12 Source- Drain Diode Forward

Is- Reverse Drain Current (A)





-Vds Drain-Source Voltage (V)

Figure 13 Safe Operation Area

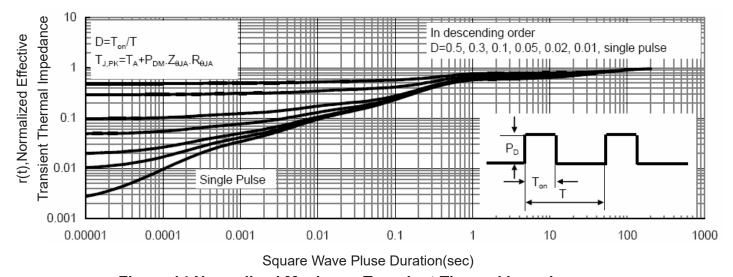


Figure 14 Normalized Maximum Transient Thermal Impedance